RD70HVF1 Transistor, 70 watt, 175 MHz, 12.5v, Mitsubishi

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RD70HVF1 RoHS Compliance, Silicon MOSFET Power Transistor, 175MHz 70W, 520MHz 50W

MFR: Mitsubishi

DESCRIPTION

RD70HVF1 is a MOS FET type transistor specifically designed for VHF/UHF High power amplifiers applications.

FEATURES

•High power and High Gain: Pout>70W, Gp>10.6dB @Vdd=12.5V,f=175MHz Pout>50W, Gp>7.0dB @Vdd=12.5V,f=520MHz
•High Efficiency: 60%typ.on VHF Band
•High Efficiency: 55%typ.on UHF Band

APPLICATION

For output stage of high power amplifiers in VHF/UHF Band mobile radio sets.

RoHS COMPLIANT

RD70HVF1-101 is a RoHS compliant products. RoHS compliance is indicate by the letter "G" after the Lot Marking.

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